

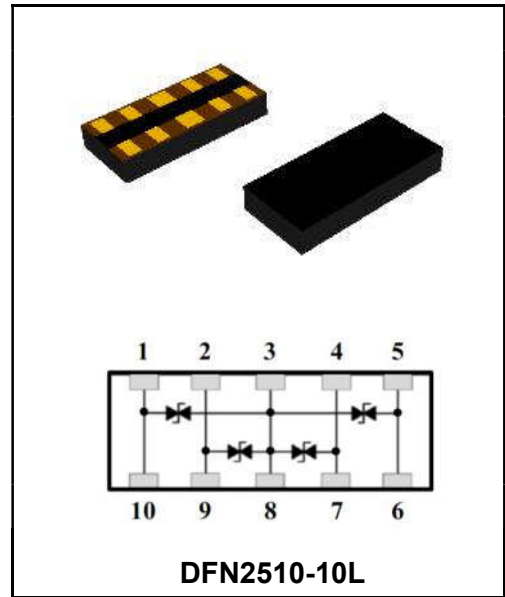
**4 Channel Ultra-low Capacitance ESD Protection**

**Features**

- ◆Ultra-Low capacitance:0.05pF(typ.)
- ◆Low leakage current(<100nA)
- ◆Fast response time(<1ns)
- ◆Bi-directional,single line protection
- ◆IEC 61000-4-2 (ESD Air): 15kV
- IEC 61000-4-2 (ESD Contact): 8kV

**Application**

- ◆USB 3.0/3.1
- ◆HDMI 1.3/1.4/2.0
- ◆RF Antenna
- ◆SATA and eSATA Interface



**Order Information**

Part Number	Package	Size (mm)	Delivery Form	Delivery Quantity
<b>ESD2510B05</b>	<b>DFN2510-10L</b>	2.50X1.00X0.50	7" T&R	3000PCS/Tape

**Limiting Values(TA = 25 °C, unless otherwise specified)**

Symbol	Parameter	Conditions	Min	Max	Unit
VESD	Electrostatic Discharge Voltage	IEC 61000-4-2; Contact Discharge	-	8	kV
		IEC 61000-4-2; Air Discharge	-	15	kV
TA	Operating Temperature Range	-	-40	90	°C
Tstg	Storage Temperature Range	-	-55	125	°C

**Electrical Characteristics(TA = 25 °C unless otherwise specified)**

Symbol	Parameter	Conditions	Min	Typ.	Max	Unit
VDC	Continuous Operating Voltage	-	-	-	5.0	V
VT	Trigger Voltage	IEC61000-4-2 8kV contactdischarge	-	450	-	V
VC	Clamping Voltage	IEC61000-4-2 8kV contactdischarge	-	40	-	V
IL	Leakage Current	DC 5V shall be appliedon mponent	-	-	100	nA
CJ	Capacitance	Measured at 10MHz	-	0.05	-	pF

Typical Characteristics

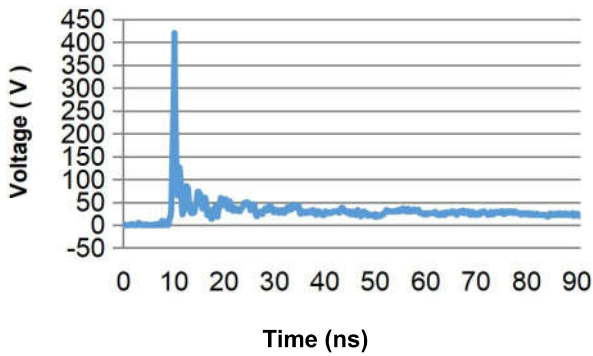


Fig.1 Typical ESD Response (IEC 61000-4-2, 8kV contact discharge)

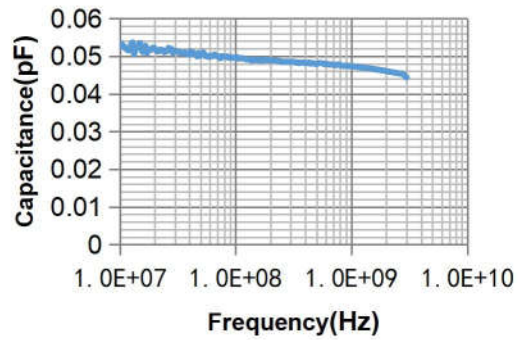


Fig.2 Typical Device Capacitance VS. Frequency

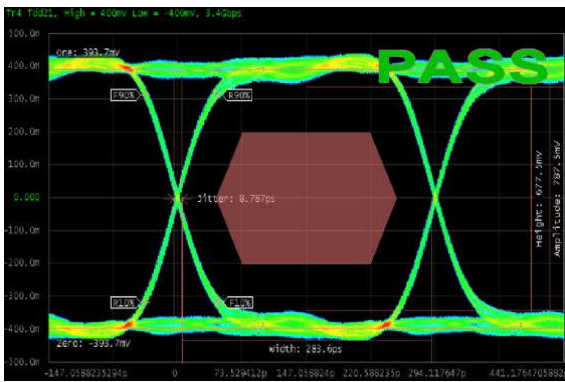


Fig.3 HDMI 1.4 Mask at 3.4 Gbps

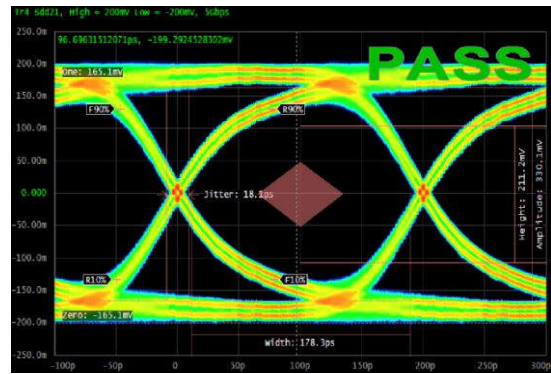
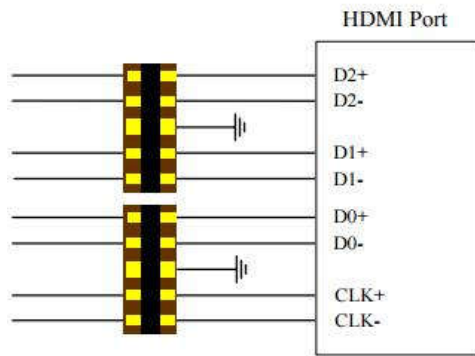


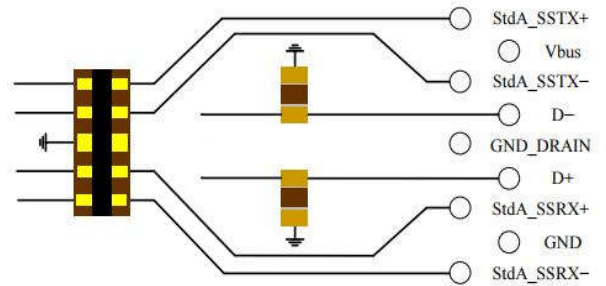
Fig.4 USB 3.0 Mask at 5.0 Gbps



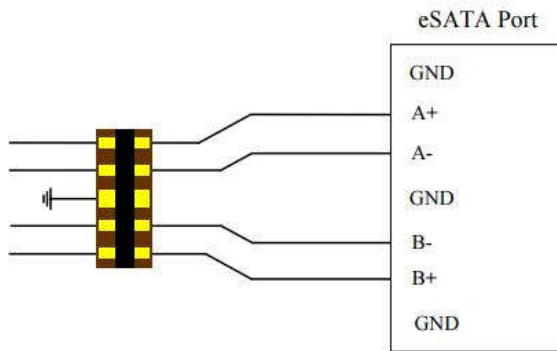
Fig.5 HDMI 2.0 Mask at 6.0 Gbps



**Fig.6 ESD Protection for HDMI**

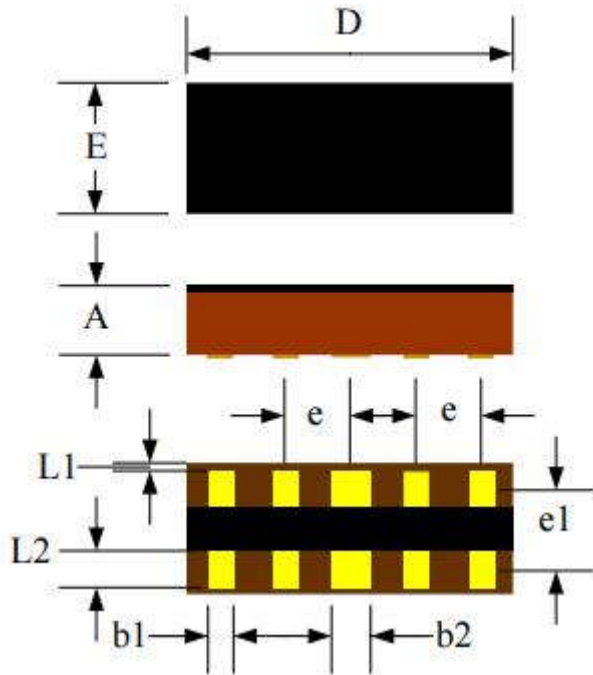


**Fig.7 ESD Protection for USB 3.0 Type A**

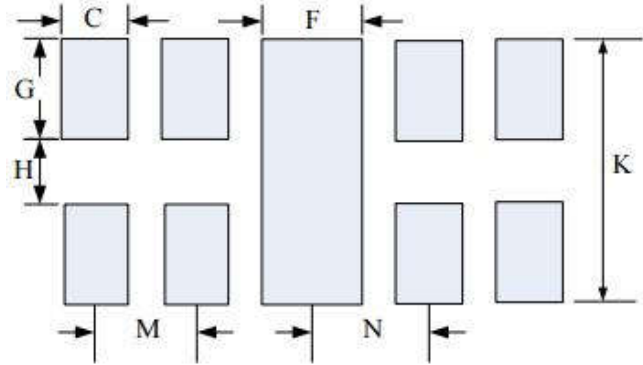


**Fig.8 ESD Protection for eSATA**

Package Dimension



**Recommended Solder Pad Footprint**



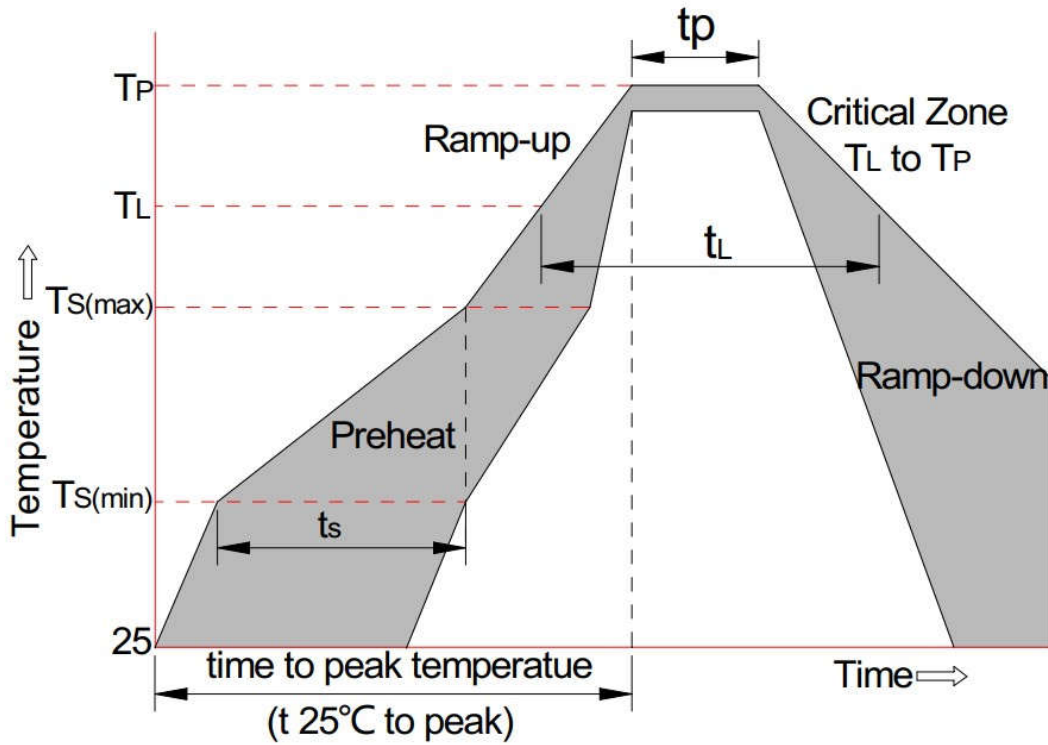
**\*Sizes in mm**

Notes:

This solder pad layout is for reference purposes only.

Dimension	Unit: Millimeters	
	Min.	Max.
A	0.40	0.60
b1	0.10	0.30
b2	0.20	0.40
D	2.40	2.60
E	0.90	1.10
e	0.40	0.60
e1	0.50	0.70
L1	0.04	0.06
L2	0.20	0.40

Dimension	Unit: Millimeters	
	Min.	Max.
C	0.20	0.30
F	0.35	0.45
G	0.55	0.65
H	0.25	0.35
K	1.40	1.60
M	0.45	0.55
N	0.45	0.55



Reflow Condition		Pb-Free Assembly
Pre-heat	-Temperature Min (Ts(min))	+150°C
	-Temperature Max(Ts(max))	+200°C
	-Time (Min to Max) (ts)	60-180 secs.
Average ramp up rate (Liquid us Temp (TL) to peak)		3°C/sec. Max
Ts(max) to TL - Ramp-up Rate		3°C/sec. Max
Reflow	-Temperature(TL)(Liquid us)	+217°C
	-Temperature(tL)	60-150 secs.
Peak Temp (Tp)		+260(+0/-5)°C
Time within 5°C of actual Peak Temp (tp)		30 secs. Max
Ramp-down Rate		6°C/sec. Max
xTime 25°C to Peak Temp (TP)		8 min. Max
Do not exceed		+260°C

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